

# **RL78/L13**

Integrate External EEPROM IC Functionality into MCU by Using Data Flash Memory (EEPROM Emulation Library) CC-RL

### Introduction

Self-programming is a function that the microcontroller to rewrite the internal flash memory by itself. RL78/L13 is equipped with the data flash memory which is suitable for data storage. Rewriting of data flash memory can be realized by the Flash Data Library (FDL) and the EEPROM Emulation Library (EEL) from Renesas Electronics Corp.

This application note explains how to hold non-volatile data simply by data flash memory and the EEL without using external EEPROM IC. It also explains how to save data to data flash memory quickly after detecting low voltage to prepare for power interruption.

User can integrate the function of external EEPROM IC into microcontroller by applying this application note.

# Correspondence between Compiler and EEL

This application note has a sample code (excluding the EEL). In order to operate this sample code, it is required to download and link EEL to the project. Refer to "6.9 How to import EEL" for details on method of linking EEL to the project.

EEL has a Renesas CC-RL version and a IAR version. However, the version of EEL supported by each sales company (each area) is different. Confirm the supported version by selecting the area on the Renesas Electronics Website (<a href="http://www.renesas.com">http://www.renesas.com</a>). Please check the manual of the EEL, and the release note (or README.txt on the download source page) before using the EEL.

Correspondence between Compiler and EEL

	EEL	Download Link	
CS+	RL78 Family EEPROM Emulation Library https://www.renesas.com/us/en/software-		
version	Pack02 tool/data-flash-libraries#overview		
e2studio	RL78 Family EEPROM Emulation Library https://www.renesas.com/us/en/software-		
version	Pack02	tool/data-flash-libraries#overview	
IAR version	RL78 Family EEPROM Emulation Library	https://www.renesas.com/us/en/software-	
	Pack02	tool/data-flash-libraries#overview	

### **Target Device**

RL78/L13

EEL used in this application note supports other devices of RL78.

RL78/D1A, RL78/F12, RL78/F13, RL78/F14, RL78/G13, RL78/G14, RL78/G1A, RL78/G1E, RL78/I1A, RL78/L1C

Confirm by the latest user's manual of the EEL about the supported device of EEL.

When applying the sample program covered in this application note to another RL78 microcontroller, conduct an extensive evaluation of the modified program.

# Contents

1. C	Overview	
1.1	Outline of the EEL	4
1.2	Outline of the FDL	4
1.3	Proper Use of the FDL and the EEL	5
1.4	Benefits and Caution Points When EEPROM IC is Replaced	8
1.4	4.1 Benefits form Replacing EEPROM IC	8
1.4	4.2 Difference from EEPROM IC	8
2. 5	Specifications	Q
2.1	Shortening of the Write Time of EEL	
2.2	EEL Architecture	
	2.1 EEL Pool	
	2.2 EEL Block	
2.3	EEL Initial Values to be Set by User	
2.4	Number of Stored User Data Items and Total User Data Size	
2.5	Notes for Using EEL	
3. (	Operation Check Conditions	23
4. F	Related Application Notes	24
5. E	Description of the Hardware	25
5.1	Hardware Configuration Example	25
5.2	List of Pins to be Used	25
6. E	Description of Software	26
6.1	Operation Outline	
6.2	File Configuration	30
6.3	List of Option Byte Settings	31
6.4	List of Constants	32
6.5	List of Variables	33
6.6	List of Functions	34
6.7	Function Specifications	35
6.8	Flowcharts	43
6.8	8.1 Overall Flowchart	43
6.8	8.2 Initialization of Peripheral Functions	43
6.8	6.8.3 Initialization of Ports	
6.8	8.4 Initialization of CPU Clock	45
6.8	8.5 Initialization of TAU0	46
	8.6 Initialization of INTP	48

	6.8.7	Initialization of LVD	48				
	6.8.8	Main Processing					
	6.8.9	Initialization of the Main Processing.	51				
	6.8.10	Initialization of EEL	52				
	6.8.11	Read Processing by EEL	53				
	6.8.12	Valid Range Check of LED blinking Data	53				
	6.8.13	EEL Function Status Check	54				
	6.8.14	Enabling TAU01	55				
	6.8.15	TAU01 Interrupt Handler	56				
	6.8.16	Disabling TAU01	57				
	6.8.17	Enabling INTP0	57				
	6.8.18	INTP0 Interrupt Handler	58				
	6.8.19	Enabling TAU00	58				
	6.8.20	TAU00 interrupt handler	59				
	6.8.21	Write by EEL	60				
	6.8.22	Disabling TAU00	60				
	6.8.23	Disabling INTP0	60				
	6.8.24	Enabling LVD Interrupt	61				
	6.8.25	LVD interrupt handler	61				
(	6.9 Ho	w to Import EEL into the Software Project	62				
	6.9.1	CS+ Version	62				
	6.9.2	IAR Version	62				
(	6.10 Mo	dification of the Sample Code	64				
7.	Same	ole Code	6E				
Ι.	Sam	JIE Gude	oo				
8	Docu	ments for Reference	65				

### Overview

There are three types of Self Programming Library; the Flash Self Programming library (FSL), the FDL, and the EEL shown in .

As libraries using data flash memory, the outline of the EEL is indicated in **1.1 Outline of the EEL** and the outline of FDL is indicated in **1.2 Outline of the FDL**. This application note explains the EEL which is indicated with the bold font in .

**Table 1.1 List of Self Programing Library** 

library FSL FDL	Code flash memory	Rewrites data in code flash memory.  Rewrites and reads data in data flash memory.
EEL	Data flash memory  Uses data flash library just like EEPROM to rew and read data.	

### 1.1 Outline of the EEL

The EEL is a software library to store the data in internal data flash memory of the RL78 microcontroller in the same way as EEPROM. In order to rewrite data flash memory with the EEL, the corresponding functions of EEL initialization and other purpose, would be called from the user-created program. The EEL allows the user to assign a 1-byte identifier (data ID: 1 to 64) to each block of data and to perform read or write operations in units of 1 to 255 bytes for each ID that is assigned (a maximum of 64 data items can be assigned to an ID).

### 1.2 Outline of the FDL

The FDL is a software library to perform operations to the data flash memory with the firmware installed on the RL78 microcontroller. In order to rewrite data flash memory with the FDL, the corresponding functions of FDL initialization and other purpose, would be called from the user-created program.

The fundamental usage of the FDL is to write data byte by byte to the data flash memory's address, which has not been written( in the blank state). However, it cannot overwrite the same address. In order to overwrite the same address, data erasing per block is required in advance.

# 1.3 Proper Use of the FDL and the EEL

There are some differences such as rewriting method, resources required, execution time, data management mechanism and so on between using the FDL and the EEL. Main features of the FDL and the EEL are shown in

Since FDL is only a fundamental access function to data flash memory, it can be customized to manage data flexibly according to the user-created program. On the other hand, EEL has the feature that development load is low because the mechanism of data management was decided in advance by the EEL.

Select the FDL or the EEL according to the requirements for application.

Table 1.21 eatures of the LDL and the LLL			
	FDL	EEL	
Rewriting method	Depends on user-created program.	Writes after changing address.	
Resources required	Small	Large	
Data size	Up to 1024 bytes	Up to 255 bytes	
Execution time	Short	Long	
Data management mechanism	None (User manage data by address)	Managed (By data number)	

Table 1.2 Features of the FDL and the EEL

**Caution**: The feature of the FDL is dependent on the upper-class layer, the application (the specification of data management).

#### (1) Rewriting Method

Writing is permitted only when the target write address of data flash memory is in the blank state. It is necessary to erase data in units of one block in advance in order to overwrite the same address. FDL itself does not have a mechanism in which data can be managed. It is necessary to consider how to manage data in the application layer (by user). On the other hand, EEL has a mechanism to manage data, and writes data with keeping changing the variable which contains an address that marks the memory in the blank state in data flash memory. Since data can be written in until the block for writing is filled with data, it is suitable for mass data storage and frequent data writing.

### (2) Resources required

Software resources required by the FDL and the EEL are shown in . The Self-RAM, stack, and data buffer have to use RAM. Since the EEL uses the FDL, the amount of the EEL ROM resources is larger than the FDL ROM resources.

Table 1.3 Software Resources of FDL/EEL (e.g. RL78/L13)

Item	Size (byte)		
item	FDL	EEL	
Self-RAM Note 1	0 to 1024	0 to 1024	
Stack	MAX 46	MAX 80	
Data buffer Note 2	1 to 1024	1 to 255	
Library size	ROM : MAX 177	ROM :MAX 3400	
	KOW . WAX 177	(FDL: 600, EEL: 2800)	

- Note 1: An area used as the working area by the EEL is called self-RAM. The self-RAM requires no user setting because it is an area that is not mapped and automatically used at execution of the EEL (previous data is discarded).
- Note 2: A RAM space required in order to input the data read and written is called a data buffer. Required size changes by the reading and writing unit. When performing 1 byte of reading and writing, a needed data buffer is 1 byte.
- Note 3: The resources given in this table are according to FDL RL78 Type04 Ver1.05 and EEL RL78 Pack02 Ver1.01. The library may change by upgrade etc. Confirm the manual of each library for the latest resource information.

### (3) Data Size

The FDL is able to read and write data up to 1024 bytes (1 block of a data flash memory). The EEL is able to read and write data up to 255 bytes. The FDL has an advantage when saving big data. The data buffer of expresses the size of the data which can be read and written at a time.

### (4) Execution Time

The execution time of the library function of FDL and EEL is shown in **Table 1.4**. The FDL without data management mechanism can read and write data at high speed.

Table 1.4 The Execution Time of the Library Function of FDL/EEL

Processing	FDL (255 bytes)	EEL (255 bytes)
Write		
FDL : PFDL_Execute(Write)	519.7[µs]	11399.7[µs]
EEL : EEL_Execute(Write)		
Read		
FDL : PFDL_Execute(Read)	167.7[µs]	179.7[µs]
EEL : EEL_Execute(Read)		
Verify		
FDL: PFDL_Execute(IVerify)	959.7[µs]	3919.7[µs]
EEL : EEL_Execute(Verify)		

Remark. The execution time described in this application note is the actual measured value calculated on operating FDL RL78 Type04 Ver1.05 or EEL RL78 Pack02 Ver1.01 on the integrated development environment CS+. The value would be different according to the individual specificities of the device and the execution condition.

### (5) Data Management Mechanism

The FDL uses address to access data flash memory. Since the address in which the newest data is stored is changed, it needs to manage the address. On the other hand, EEL manages data by data ID. Therefore, it is not necessary to manage the address in which the newest data is stored when using the EEL.

### 1.4 Benefits and Caution Points When EEPROM IC is Replaced

This section explains benefits when replacing the function of EEPROM IC with data flash memory by using EEL, and the difference from EEPROM IC.

### 1.4.1 Benefits form Replacing EEPROM IC

The benefits of replacing from EEPROM IC are shown below.

- Since external EEPROM IC becomes unnecessary, parts cost reduction and small footprint are realizable.
- Since it is the operation completed inside device, it is not necessary to perform serial communication. The serial communication pins of microcontroller can be used by other functions. In addition, the value which was written can be confirmed directly with a debugger at the time of the software development.
- Since serial communication is unnecessary, processing time can be reduced. (However, it is dependent on data structure.) In EEPROM IC, the serial communication time + the write completion time (several milliseconds) are taken for the processing time.
- Since data is managed by data ID, it is not necessary to care about address.

### 1.4.2 Difference from EEPROM IC

The difference with the case where EEPROM IC is used is shown below.

- Since it is emulation, the size of the flash memory which can be used by user decreases. Refer to "2.4 Number of stored user data items and total user data size" for how to calculate the space available to the user.
- The program which communicates with EEPROM IC is not required. Instead, a program just like the FDL or the EEL is necessary.
- The maximum number of data items is 64 and the maximum size of one data item is 255 byte. Refer to the user's manual of the EEL for more information about the number of data items.

# 2. Specifications

In this application, LED0 or LED1 blinks 10 times by a keypress. The data used for LED blinking is saved to data flash memory when the supply voltage becomes too low. The saved data is read when system restarts, and the interrupted blinking processing is continued.

When reset is ended, the system reads the blinking state data (target LED for blinking, and the remaining times of LED blinking) by EEL from data flash memory where the data has been saved.

Next, after completing 10 times blinking at intervals of 500 ms according to the blinking state data, the LED stops blinking and the system becomes the waiting state for keypress.

If the key is pressed in a state in which no LED is blinking, the LED that had not been blinking just before will start to blink. The keypress becomes invalid while LED is blinking.

The fall of power supply voltage is detected by LVD function. If the fall of power supply voltage is detected, the LED blinking state data (target LED for blinking, and the remaining times of LED blinking) is saved to data flash memory by the EEL, LED3 which shows the completion of data saving will be lit up, and then the mode moves to the STOP mode.

Moreover, if an error occurs when accessing data flash memory with EEL functions, LED0 and LED1 will be lit up and the mode shifts into the STOP mode.

The structure of the data to be saved is shown in **Figure 2.1**. Higher 4 bits of this one byte user data indicates target LED for blinking and lower 4 bits indicate the remaining times of LED blinking. The example data in **Figure 2.1**shows that the rest of the LED1's blinking times is 5.

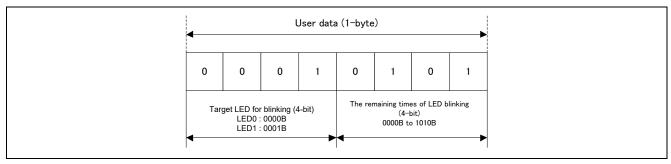


Figure 2.1 Stored Data

**Table 2.1**shows the required peripheral functions and their uses. **Figure 2.2** shows overall picture of application. **Figure 2.3** shows operation outline.

Peripheral Function	Use
LVD	Supply voltage (VDD) monitoring
External interrupt (INTP0)	Key for operation switching
P05	LED lighting control (LED0)
P45	LED lighting control (LED1)
P41	LED lighting control (LED3)
Timer array unit (TAU) 0 channel 0	Generation of the wait time for chattering evasion of
	keypress (10ms)
TAU0 channel 1	Generation of LED blinking interval time (500ms)

Table 2.1 Peripheral Functions to be Used and their Uses

R01AN6457EJ0100 Rev.1.00 June. 24. 22

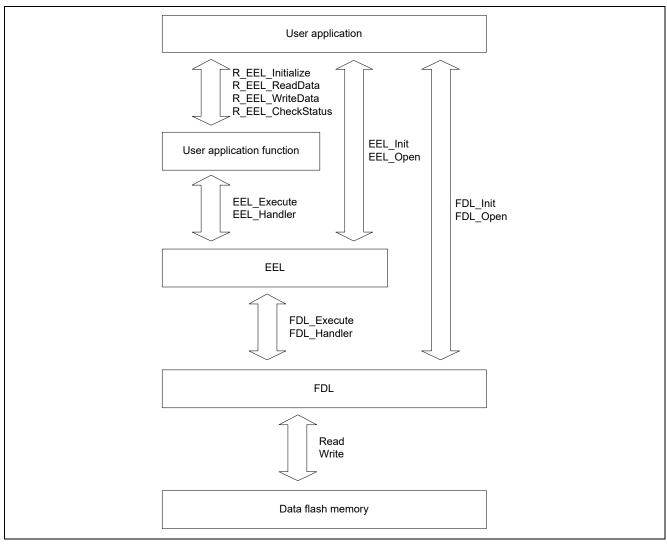


Figure 2.2 Overall Picture of Application

It is necessary to set data flash memory to the state that accessing data flash memory is permitted, or to secure the resource used by FDL/EEL by performing Init/Open of FDL/EEL, in order to access data flash memory from user application. The reading and writing to data flash memory are enabled by performing Startup of EEL after the Init/Open processing.

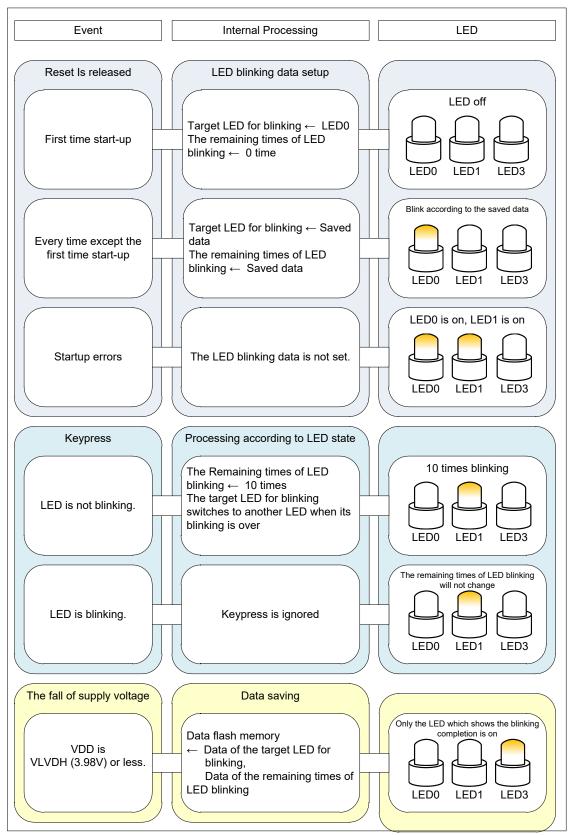


Figure 2.3 Operation Outline

# 2.1 Shortening of the Write Time of EEL

In order to access data flash memory from user application using the EEL, it is necessary to set data flash memory to the state that accessing the data flash memory is permitted, or to secure the resource used by FDL/EEL. Therefore, the EEL realizes the above-mentioned processes by calling some library functions. Required processes are as follows.

- · FDL Init function: Initialization of RAM used by FDL.
- FDL\_Open function: Set data flash memory to the state that accessing the data flash memory is permitted.
- EEL Init function: Initialization of RAM used by EEL.
- EEL Open function: Set data flash memory to the state that can be managed.
- EEL\_Execute function (STARTUP command): Changing into the state in which EEPROM emulation execution is possible.

However, if the above-mentioned preparation processings are performed at a low voltage, it may become power disconnect during the data saving processing. Therefore, in this application note, in order to shorten the data saving time, the data saving processing done by EEL is divided into two phases which are executed separately, the preparation phase and the saving phase.

**Figure 2.4** shows the data saving processing when it is performed by a batch processing. **Figure 2.5** shows the data saving processing when it is performed by a two-step processing. The saving phase takes 991[μs] in the case of batch processing, and takes 683[μs] in the case of two-step processing.

Remark. The measurements described in this application note are the actual measured value calculated by using EEL RL78 Pack02 Ver1.01 on the integrated development environment CS+.

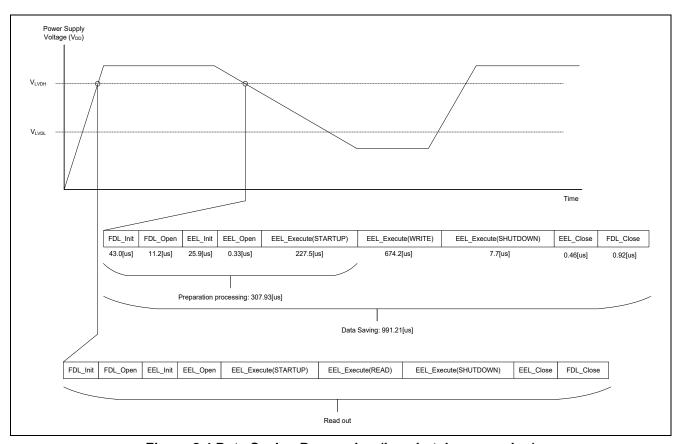


Figure 2.4 Data Saving Processing (by a batch processing)

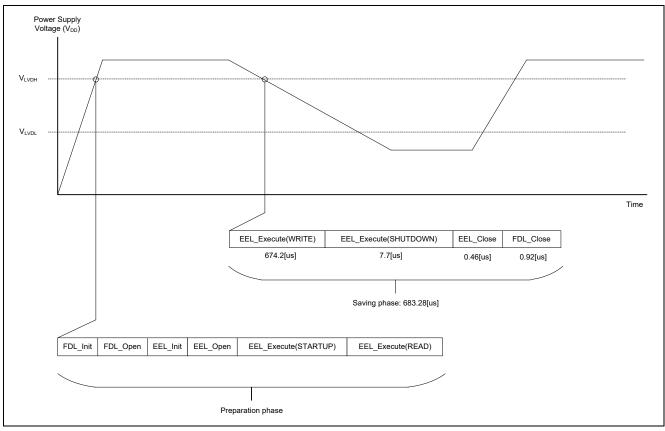


Figure 2.5 Data Saving Processing (by a two-step processing)

### 2.2 EEL Architecture

The operation principle of the EEL is explained. The EEL manages data in the data area and manages data ID in the reference area. These areas are configured in the same block and managed by each block. The next block will be used if unused area of the block currently used is run out. This chapter explains how to use the data flash memory in the EEL.

### 2.2.1 EEL Pool

The EEL pool is a user-defined data flash area that is accessible by the EEL. The user-created program can access the data flash only by using this EEL pool in the data flash via the EEL.

The EEL pool size must be specified with the number of blocks in the data flash of the target device. For the procedure to specify the number of blocks, see Section 2.3 EEL Initial Values to be set by User.

The EEL pool is divided into 1024-byte blocks. Each block has a state which indicates the current usage of the block.

State	Description	
	Only a single EEL block is active at a time to store defined data. The active block	
Active	circulates in data flash blocks allocated in the EEL pool.	
	No data is stored in invalid blocks. EEL blocks are marked as invalid by the EEL or	
Invalid	become invalid in the case of erasure blocks.	

Figure 2.6 shows an exemplary pool configuration for a device with 4 KB data flash.

When no writable area is remaining in the active block (block 1 in the example) and data can no longer be stored (failure in write command), a new active block is selected in a cyclic manner and the current valid data set is copied to this new active block. This process is referred to as refresh. After the EEL\_CMD\_REFRESH command is executed, the previous active block becomes invalid and only a single active block exists.

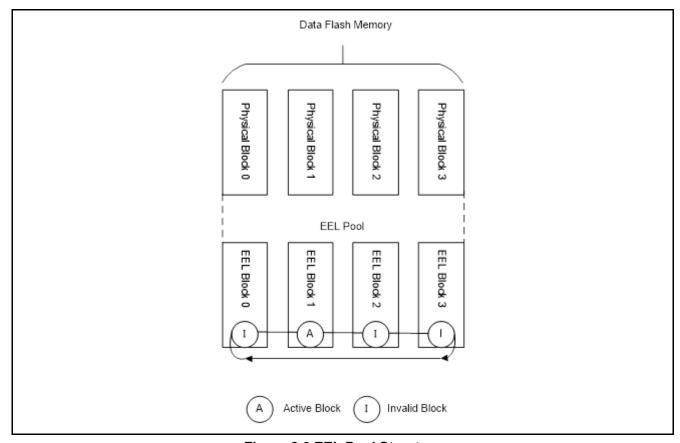


Figure 2.6 EEL Pool Structure

The overall life cycle of a block in the EEL pool is shown in Figure 2.7. The EEL block switches between active and invalid state.

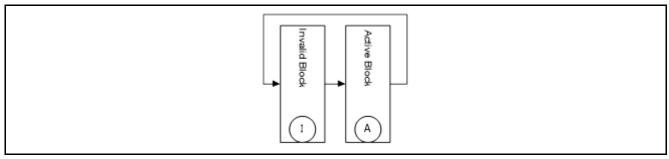


Figure 2.7 Life Cycle of an EEL Block

### 2.2.2 EEL Block

**Figure 2.8 EEL** Block Structure (Example of RL78/L13 (R5F10WMG)) shows detailed block structure used by the EEL. The EEL block is divided into three utilized areas: the block header, the reference area and the data area.

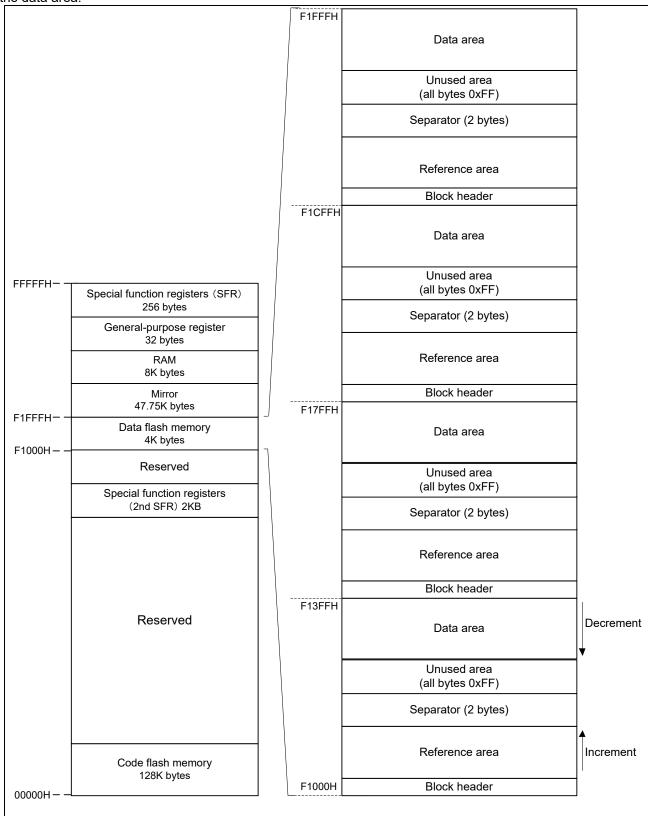


Figure 2.8 EEL Block Structure (Example of RL78/L13 (R5F10WMG))

**Table 2.1 Components of EEL Block** 

Name	Description	
Block header	The block header contains all block status information needed for the block management	
	within the EEL-pool. It has a fixed size of 8 bytes.	
Reference area	The reference area contains reference data which are required for the management of data.	
	When data is written, this area extends in the address increment direction.	
Data area	The data area contains user data. When data is written, this area extends in the address decrement direction.	

Between reference area and data area, there is an unused area. With each EEL data update (i.e. the data is written), this area is reduced successively. However, at least two bytes of space is always required in between reference area and data area for management and separation of these areas. This is indicated by the separator in **Figure 2.8**.

# 2.3 EEL Initial Values to be Set by User

As the initial values for the EEL, be sure to set the items indicated below. In addition, before executing the EEL, be sure to execute the high-speed on-chip oscillator. The high-speed on-chip oscillator must also be activated when using the external clock. Parentheses indicated on the right-hand side of each setup are connected with the numbers in the following page.

Setup of each item has been tailored to this application.

<FDL user include file (fdl descriptor.h)> Note 1,2

#define	FDL_SYSTEM_FREQUENCY	24000000	:(1) Operation frequency
#define	FDL WIDE VOLTAGE MODE		:(2) Voltage mode
#define	FDL_POOL_BLOCKS	0	:(3) FDL pool size
#define	EEL_POOL_BLOCKS	4	:(4) EEL pool size

<EEL user include file (eel\_descriptor.h)>Note 1, 2

```
#define EEL_VER_NO 1 :(5) Number of stored data items
```

```
< EEL user type include file (eel_user_types.h)> Note 1, 2
```

```
typedef eel_u08 type_A; :(6) Data size
```

```
<EEL user-created progaram file (eel_descriptor.c)> Note 1, 2
```

```
__far const eel_u08 eel_descriptor[EEL_VAR_NO+2] = :(7) Data size of the data ID
{
    (eel_u08)(EEL_VAR_NO), /* variable count */ \
    (eel_u08)(sizeof(type_A)), /* id = 1 */ \
    (eel_u08) (0x00), /* zero terminator */ \
};
```

- Note 1: The macros and macro names that are being used have common parameters with the EEL, so changes should be made to numerical values only.
- Note 2: After initializing the EEPROM emulation blocks (after executing the EEL\_CMD\_FORMAT command), do not change the values. If the values are changed, reinitialize the EEL blocks (by executing the EEL\_CMD\_FORMAT command).

### (1) Operation frequency

This sets an operation frequency which is used in RL78 microcontrollers. Note1 The setting value is set to the FDL\_Init frequency parameter by the following expressions. In this application note, since the operation frequency of CPU is 24 MHz, it is set to 24.

Note1: This setting is a value required to control data flash memory. This setting does not change the operation frequency of RL78 microcontrollers. In addition, this operation frequency is not the frequency of the high-speed on-chip oscillator.

### (2) Voltage mode

This sets the voltage mode of data flash memory. Note 2
FDL\_WIDE\_VOLTAGE\_MODE is not defined: Full-speed mode
FDL\_WIDE\_VOLTAGE\_MODE is defined: Wide voltage mode
This application note does not define FDL\_WIDE\_VOLTAGE\_MODE because it is operated in full speed mode.

Note 2: For details of the voltage mode, see the corresponding RL78 microcontrollers user's manual.

# (3) FDL pool size Note 3 Specify 0.

Note 3: A user defined data flash area which is accessible by the FDL.

### (4) EEL pool size Note 4

The number of blocks in the data flash memory of the target device must be specified as the number of blocks in the EEL pool.

Note 4: Specify 3 (3 blocks) or a greater value (recommended).

### (5) Number of stored data items

Specify the number of data items to be used in the EEPROM emulation. A value of 1 to 64 can be set. In this application note, since one kind of data is managed, the number of stored data items is set to 1.

### (6) Data size registration

The data size of every data ID is registered into an EEL descriptor table.

There are 8 standarized sizes: type\_A, type\_B, type\_C, type\_D, type\_E, type\_F, type\_X, and type\_Z. It is necessary to change size according to the size of the user data.

In this application note, since one data type of 1-byte (LED blinking state) is managed, type\_A which is 1-byte long, is used for data ID1.

### (7) Data size of data ID

A table to define the data size of each data ID is provided below. This is called an EEL descriptor table. The EEL can only add identifiers while the program is running. Data to be written must be registered in the

EEL descriptor table in advance like the processing described in (6).

### **EEL Descriptor Table**

\_\_far const eel\_u08 eel\_descriptor [ Number of stored data items (1) + 2 ]

EEL_VAR_NO
Byte size of data ID1 (type_A)
0x00

RENESAS

### · EEL\_VAR\_NO

User-specified number of data items used in the EEL

- Byte size of Data IDx
   User-specified size of user data (in bytes)
- Termination area (0x00)

  Specify 0 as the termination information.

### 2.4 Number of Stored User Data Items and Total User Data Size

The total size of user data that can be used in the EEPROM emulation is limited. If refresh processing is taken into consideration, it is need to place all of the user data and an unused area which is big enough for one or more data in one block.

The number of stored data items that can be used differs depending on the size of user data that is actually stored.

The following shows the calculation method of the size which can actually be used in the writing of user data, and the maximum number of times one block can be written with user data.

Maximum usable size of one block that can be used to write the user data

Size of one block of data flash memory: 1024 bytes

Size required for EEPROM emulation block management: 8 bytes

Free space necessary as termination information (separator): 2 bytes

Maximum usable size of one block = 1024 bytes - 8 bytes - 2 bytes = 1014 bytes

[Calculating the size for writing each user data item]

Size of each written user data item = data size + reference data size (2 bytes)

Since the size of the data written in in this application note is 1 byte, the size of user data will be 3 bytes.

[Number of times one block can be written]

Because the maximum usable size of one block is 1014 bytes and the user data size is 3 bytes:

Number of times one block can be written = 1014 / 3 = 338 times

It is necessary to perform refresh processing for every 338 times writing in this application note. Refresh processing is performed within preparation processing (Refer to 2.1 Shortening of the Write Time of EEL). At the time of doing refresh processing, preparation processing time is longer for 6.74[ms] in comparison with usual time.



# 2.5 Notes for Using EEL

Notes when using EEL are shown below.

- · The data flash memory cannot be read during data flash memory operation by the EEL.
- · The watchdog timer does not stop during the execution of the EEL.
- The EEL does not support multitask execution. Do not execute the EEL functions during interrupt processing.
- Before starting the EEPROM emulation, be sure to start up the high-speed on-chip oscillator first. The high-speed on-chip oscillator must also be activated when using the external clock.
- In address above 0xFFE20 (0xFE20), do not place data buffer (argument) or stack which is used by EEL functions and FDL functions.
- To use the data flash memory for EEPROM emulation, it is necessary to execute the EEL\_CMD\_FORMAT command upon first starting up to initialize the data flash memory and make it usable as EEPROM emulation blocks.
- · It is recommended to use at least three blocks of the data flash memory in order to use the EEL.
- The EEL does not support multitask execution. When executing an EEL function on the OS, do not
  execute in from two or more tasks.
- About an operation frequency of RL78 microcontrollers and an operation frequency value set by the initializing function (FDL\_Init), be aware of the following points:
  - When using a frequency lower than 4 MHz as an operation frequency of RL78 microcontrollers, only 1 MHz, 2 MHz and 3 MHz can be used (frequencies other than integer values like a 1.5 MHz cannot be used). Also, set an integer value 1, 2, or 3 to the operation frequency value set by the initializing function.
  - When using a frequency of 4 MHz or higher Note as an operation frequency of RL78 microcontrollers, a certain frequency can be used as an operation frequency of RL78 microcontrollers.
  - This operation frequency is not the frequency of the high-speed on-chip oscillator.

Note: For a maximum frequency, see the target RL78 microcontroller user's manual.

# 3. Operation Check Conditions

The sample code described in this application note has been checked under the conditions listed in the table below.

**Table 3.1 Operation Check Conditions** 

Item	Description	
Microcontroller used	RL78/L13(R5F10WMGA)	
Operating frequency	<ul> <li>□ High-speed on-chip oscillator (fHOCO) clock: 24 MHz (Standard)</li> <li>□ CPU/peripheral hardware clock (fcLκ): 24 MHz</li> </ul>	
Operating voltage	5.0V (Operation is possible over a voltage range of 4.1V to 5.5V)	
	LVD operation (VLVI): Reset mode	
	V <sub>LVDH</sub> (rising edge 4.06V / falling edge 3.98V)	
	V <sub>LVDL</sub> (falling edge 2.75V)	
Integrated development environment	CS+ for CC V8.07.00 from Renesas Electronics Corp	
(CS+)		
C compiler (CS+)	CC-RL V1.11.00 from Renesas Electronics Corp	
Integrated development environment	e 2 studio V2022-01 (22.1.0) from Renesas Electronics Corp	
(e 2 studio)		
C compiler (e 2 studio)	CC-RL V1.11.00 from Renesas Electronics Corp	
Integrated development environment	IAR Embedded Workbench for Renesas RL78 V4.21.3 from IAR	
(IAR)	Systems	
C compiler (IAR)	IAR C/C++ Compiler for Renesas RL78 V4.21.3.2447 from IAR	
	Systems	
FDL	FDL RL78 Type04 Ver1.05 <sup>None</sup>	
	Type04 package Ver.2.00	
EEL	EEL RL78 Pack02 Ver2.00 <sup>None</sup>	
	Pack02 package Ver.2.00	
Board to be used	RL78/L13 Target board (QB-R5F10WMG-TB)	

Note: Use and evaluate the latest version.

# 4. Related Application Notes

The application notes that are related to this application note are listed below for reference. RL78 Family EEPROM Emulation Library Pack02 (R01US0068EJ) User Manual Data Flash Access Library (Type T02 (Tiny), European Release) (R01US0061ED0130) Application Note

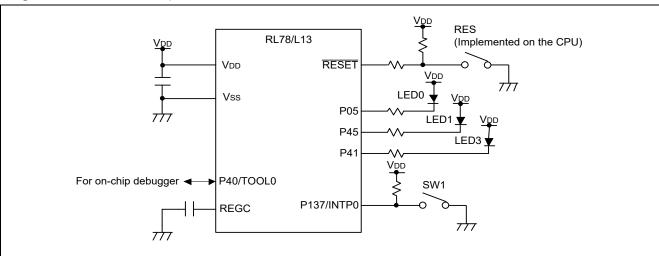
EEPROM Emulation Library (Type T02 (Tiny), European Release) (R01US0070ED0110) Application Note



# 5. Description of the Hardware

# 5.1 Hardware Configuration Example

Figure 5.1 shows an example of the hardware connection.



Cautions: 1. The purpose of this circuit is only to provide the connection outline and the circuit is simplified accordingly. When designing and implementing an actual circuit, provide proper pin treatment and make sure that the hardware's electrical specifications are met (connect the input-only ports separately to VDD or Vss via a resistor).

2. VDD must be held at not lower than the reset release voltage (VLVDH) that is specified as LVD.

Figure 5.1 Connection Example

### 5.2 List of Pins to be Used

**Table 5.1** lists pins to be used and their functions.

Table 5.1 Pins to be Used and their Functions

Pin Name	I/O	Description
P05	Output	LED On (LED0) control port
P45	Output	LED On (LED1) control port
P41	Output	LED On (LED3) control port
P137/INTP0	Input	Key input (SW1) port

# 6. Description of Software

### 6.1 Operation Outline

In this application, LED0 or LED1 blinks 10 times by a keypress. The data used for LED blinking is saved to data flash memory when the supply voltage becomes too low. The saved data is read when system restarts, and the interrupted blinking processing is continued.

When reset is ended, the system reads the blinking state data (target LED for blinking, and the remaining times of LED blinking) by EEL from data flash memory where the data has been saved.

Next, after completing 10 times blinking at intervals of 500 ms according to the blinking state data, the LED stops blinking and the system becomes the waiting state for keypress.

If the key is pressed in a state in which no LED is blinking, the LED that had not been blinking just before will start to blink. The keypress becomes invalid while LED is blinking.

The fall of power supply voltage is detected by LVD function. If the fall of power supply voltage is detected, the LED blinking state data (target LED for blinking, and the remaining times of LED blinking) is saved to data flash memory by the EEL, LED3 which shows the completion of data saving will be lit up, and then the mode moves to the STOP mode.

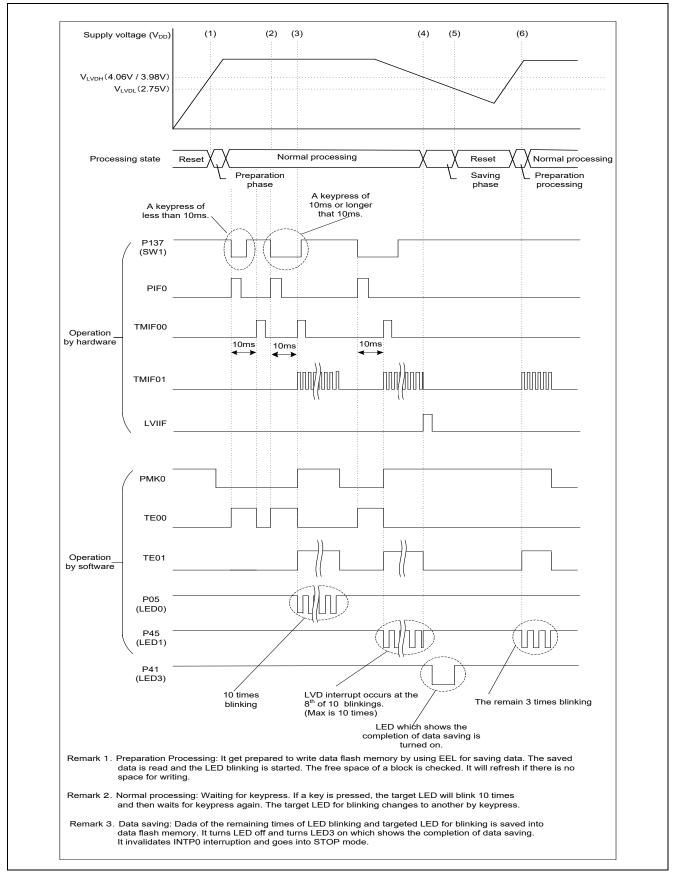
Moreover, if an error occurs when accessing data flash memory with an EEL function, LED0 and LED1 will be lit up and the mode shifts into the STOP mode.

- 1. Sets the input and output ports.
  - LED lighting control (for LED0, LED1, LED3): Configure P05, P45, and P41as the output ports. (LED0, LED1, and LED3 are off.)
  - · Keypress: Configure P137/INTP0 for detecting INTP0 falling edges. (Interrupt servicing disabled)
- 2. Start EEPROM emulation by doing the RAM initialization processing of FDL/EEL and the preparation processing.
  - Specifically, functions are called in following order.
  - FDL\_Init, FDL\_Open, EEL\_Init, EEL\_Open, EEL\_Execute(Startup)
- 3. LED blinking state (Data ID: 1) is read and then the target LED will blinked at intervals of 500 ms according to this LED blinking state.
  - · Higher 4 bits of the read data show the target LED for blinking (0000B: LED0, 0001B: LED1). And lower 4 bits show the data (Range: 0000B 1010B) of remaining times of LED blinking.
- The target LED for blinking to is set as LED0 and the data of remaining times of LED blinking is set as 0, when data does not exist.
  - · Blinking according to the read data is started.
  - · EEL Execute (Read) function is used for reading of data.
- 4. Ensure the space for data writing via evaluating the free space in a block before writing the data.
  - If free space is lower than 3 bytes (smaller than the size of user data), perform refresh processing to secure a space in another block and move the latest data.
  - · If free space is 3 bytes or more, refresh processing is not performed.
- 5. A push on a switch will blink LED 10 times.
  - Interrupt processing is started upon detection of a P137/INTP0 falling edge. Chattering is detected and, if the on state of the input lasts about 10 ms, it is recognized as a valid keypress and the LED blinking is started.
  - · Target LED for blinking is changed at every keypress.
  - The next keypress can't be accepted during the period from pressing key to the end of the LED blinking.
- 6. When a LVD interrupt occurs, the remaining times of LED blinking and the number of the target LED for blinking will be saved to data flash memory. The LED3 turns on to show completion of data saving. Then FDL/EEL will be stopped and system will go into STOP mode. Specifically, after functions are called in following order, STOP command is executed.
  - EEL\_Execute(Write), EEL\_Execute(Shutdown), EEL\_Close、FDL\_Close
- 7. If an error occurs when accessing data flash memory by the EEL, it will go to the stop mode after stopping FDL/EEL and turning on both LED0 and LED1.

RENESAS

Specifically, after functions are called in following order, STOP command is executed. EEL\_Execute(Shutdown), EEL\_Close, FDL\_Close If reset occurs, it will return to 1.

Figure 6.1 shows the timing chart.



**Figure 6.1 Timing Chart** 

### (1) Release from the reset state

After reset is ended the CPU starts running, initialization of RAM used by FDL/EEL and the LED blinking data reading are performed. Then LED linking is started according to the read data.

### (2) Keypress of SW1

The count of the interval timer for chattering evasion is started.

### (3) Detection of keypress

It will be regarded as a valid keypress if the detection performed 10 ms after the previous keypress shows that SW1 is still being pressed. The interval timer of 500 ms is started, and LED goes to blink.

### (4) Low voltage detection

LED blinking data (the remaining times of LED blinking, the target LED for blinking) will be written in data flash memory (Data ID: 1), and the blinking LED will be off. Moreover, after turning on LED (LED3) which shows the completion of data saving, It invalidates INTP0 interruption (operation of SW1 is ignored), and goes into STOP mode. In the example of Figure 6.1, LED blinking data is set to 03H (the rest of the LED0's blinking times is 3).

### (5) Reset occurring

If voltage becomes below 2.75V (V<sub>LVDL</sub> falling edge), reset by LVD will occur.

#### (6) Data saving

LED corresponding to the data saving blinks when the reset is ended. In the example of Figure 6.1, LED0 blinks 3 times.

R01AN6457EJ0100 Rev.1.00 June. 24. 22



# **6.2** File Configuration

The files used for the sample code is shown in **Table 6.1**. Files that are automatically generated by the integrated development environment are excluded.

Table 6.1 List of Additional Functions and Files

File Name	Outline	Remarks
r_eel_function.c	Source file for the data saving	Additional functions:
	function	R_EEL_Initialize
		R_EEL_CheckStatus
		R_EEL_ReadData
		R_EEL_CheckDataRange
		R_EEL_WriteData
r_eel_function.h	Header file for the data saving function	-
fdl descriptor.c	FDL descriptor source file	Same in both complier ( CS+ version
lui_descriptor.c	T DE descriptor source lile	and IAR version)
fdl_descriptor.h	FDL descriptor header file	Same in both complier ( CS+ version
		and IAR version)
eel_descriptor.c	EEL descriptor source file	Same in both complier ( CS+ version
		and IAR version)
eel_descriptor.h	EEL descriptor header file	Same in both complier ( CS+ version
C. H. I. Note 1		and IAR version)
fdl.h <sup>Note 1</sup>	Header file of FDL	Same in both complier ( CS+ version
eel.h <sup>Note 1</sup>	11	and IAR version)
eei.nivote	Header file of EEL	Same in both complier ( CS+ version
and turned b	Lloader file of EEL type	and IAR version)
eel_types.h	Header file of EEL type definition	Same in both complier ( CS+ version and IAR version)
eel user types.h		Same in both complier ( CS+ version
eei_usei_types.fi	Header file of EEL user type definition	and IAR version)
fdl.lib <sup>Note 1</sup>	FDL	CS+ version, e2 studio version
fdl.r87 <sup>Note 1</sup>	FDL	IAR version
eel.lib <sup>Note 1</sup>	EEL	CS+ version, e2 studio version
eel.r87 Note 1	EEL	IAR version
r_eel.dr Note 2	Link directive file	CS+ version, e2 studio version
trio_InkR5F10WMG.icf Note 2	Link directive file	IAR version

Note 1: It is a file which needs to be added separately. Refer to the cover sheet "Correspondence between Compiler and EEL" for more information.

Note 2: Depending on the device to be used, change may be required for the contents.

# **6.3** List of Option Byte Settings

**Table 6.2** summarizes the settings of the option bytes.

**Table 6.2 Option Byte Settings** 

Address	Setting	Description
000C0H/010C0H	11101111B	Disables the watchdog timer.
		(Stops counting after the release from the reset status.)
000C1H/010C1H	01110010B	LVD interrupt & Reset Mode
		Detection voltage $V_{\text{LVDH}}$ :  Rising edge 4.06V/Falling edge 3.98V $V_{\text{LVDL}}$ :  Rising edge 2.75V
000C2H/010C2H	11100000B	high-speed on-chip oscillator HS mode 24MHz
000C3H/010C3H	10000100B	Enables the on-chip debugger

# **6.4** List of Constants

**Table 6.3** lists the constants for the sample program.

# **Table 6.3 Constants**

Constant	Setting	Description
DATA_ID	0x01	Data ID of EEL
RET_OK	0x00	Normal response
RET_NG_DEVICE	0x01	Device exception
RET_NG_NODATA	0x02	No stored data
RET_NG_RANGE	0x03	The data is out of the valid range.
USER_DATA_SIZE	0x03	User data size
SHIFT_NUM	0x04	The number of bits to be shifted for LED
		blinking data
STATUS_PENDING	0xFF	Pending status
BLINK_LED_MAX	0x01	The maximum of the blinking LED's number
BLINK_NUM_MAX	0x0A	The maximum of LED blinking times
BLINK_LED0	0x00	Target LED for blinking: LED0
BLINK_LED1	0x01	Target LED for blinking: LED1
LED0	P0.5	LED0 control port (CS+ version)
LEDO	P0_bit.no5	LED0 control port (IAR version)
LED1	P4.5	LED1 control port (CS+ version)
LEDI	P4_bit.no5	LED1 control port (IAR version)
LED3	P4.1	LED3 control port (CS+ version)
LED3	P4_bit.no1	LED3 control port (IAR version)
LED_ON	0	LED ON level
LED_OFF	1	LED OFF level
SW1	P13.7	SW1 control port (CS+ version)
	P13_bit.no7	SW1 control port (IAR version)
SW_ON	0	Keypress level of SW
SW_OFF	1	Not the keypress level of SW
BLINK_LED_MASK	0xF0	Mask for blinking target in LED blinking data
BLINK_NUM_MASK	0x0F	Mask for blinking times in LED blinking data

#### **List of Variables** 6.5

Table 6.4 lists the global variables.

# **Table 6.4 Global Variables**

Туре	Variable Name	Contents	Function Used
volatile uint8_t	g_blink_led	Target LED for blinking	main
			r_tau0_channel0_interrupt
			r_tau0_channel1_interrupt
volatile uint8_t	g_blink_num	Blink count	main
			r_tau0_channel0_interrupt
			r_tau0_channel1_interrupt
volatile uint8_t	g_lvd_flag	Supply voltage fall detection flag	main
			r_lvd_interrupt

#### 6.6 **List of Functions**

**Table 6.5** gives a list of functions that are used by this sample program.

**Table 6.5 Functions** 

Function Name	Outline	
R_Systeminit	Initialization of peripheral functions	
R_PORT_Create	Initialization of the port	
R_CGC_Create	Initialization of CPU clock	
R_TAU0_Create	Initialization of TAU0	
R_INTC_Create	Initialization of INTP	
R_LVD_Create	Initialization of LVD	
main	Main processing	
R_MAIN_UserInit	Initialization of the main processing	
R_EEL_Initialize	Initialization of EEL	
R_EEL_ReadData	Read by EEL	
R_EEL_CheckDataRange	Valid range check of LED blinking data	
R_EEL_CheckStatus	EEL function status check	
R_TAU0_Channel1_Start	Enabling TAU01	
r_tau0_channel1_interrupt	TAU01 interrupt handler	
R_TAU0_Channel1_Stop	Disabling TAU01	
R_INTC0_Start	Enabling INTP0	
r_intc0_interrupt	INTP0 interrupt handler	
R_TAU0_Channel0_Start	Enabling TAU00	
r_tau0_channel0_interrupt	TAU00 interrupt handler	
R_EEL_WriteData	Write by EEL	
R_TAU0_Channel0_Stop	Disabling TAU00	
R_INTC0_Stop	Disabling INTP0	
R_LVD_InterruptMode_Start	Enabling LVD interruption	
r_lvd_interrupt	LVD interrupt handler	
FDL_Init	Initialization of FDL	
FDL_Open	FDL set up	
FDL_Close	Stop FDL	
EEL_Init	Initialization of RAM used by EEL	
EEL_Open	EEL set up	
EEL_Close	Stop EEL	
EEL_Execute	Execution of the data flash operation by each command	
EEL_Handler	Control of EEL during program execution	
EEL_GetSpace	Confirmation of free space of EEL block	

# 6.7 Function Specifications

This section describes the specifications for the functions that are used in the sample code. Each function has included r\_cg\_macrodriver.hHeader.

### R\_Systeminit

Synopsis Initialization of peripheral functions

Header None

**Declaration** void R\_Systeminit(void)

**Explanation** Initializes peripheral functions used in this application note.

Arguments None Return value None

### R PORT Create

Synopsis Initialization of ports

**Header** r\_cg\_port.h

**Declaration** void R\_PORT\_Create(void)

**Explanation** Initializes ports.

Arguments None Return value None

### R\_CGC\_Create

Synopsis Initialization of CPU clock

Header r\_cg\_cgc.h

Declarationvoid R\_CGC\_Create(void)ExplanationInitializes the CPU clock.

Arguments None Return value None

### R TAU0 Create

Synopsis Initialization of TAU0

**Header** r\_cg\_timer.h

**Declaration** void R\_TAU0\_Create(void)

**Explanation** Initializes TAU0 in order to use TAU00 and TAU01 as interval timers.

Arguments None Return value None

R01AN6457EJ0100 Rev.1.00

Page 35 of 65

# Integrate External EEPROM IC Functionality into MCU by Using Data

Flash Memory (EEPROM Emulation Library)

### R\_INTC\_Create

RL78/L13

Initialization of INTP **Synopsis** 

Header r\_cg\_intc.h

**Declaration** void R\_INTC\_Create(void)

Initializes INTP. **Explanation** 

None **Arguments** Return value None

### R LVD Create

**Synopsis** Initialization of LVD

Header r\_cg\_lvd.h

void R\_LVD\_Create(void) **Declaration** 

**Explanation** Initializes LVD.

**Arguments** None None Return value

### main

**Synopsis** Main Processing

Header r\_cg\_tau.h

> r\_cg\_intc.h r\_eel\_function.h r\_cg\_userdefine.h

Declaration void main(void)

Main processing is performed. **Explanation** 

None **Arguments** Return value None

### R MAIN UserInit

**Synopsis** Initialization of the Main Processing

Header r lvd.h

r\_eel\_function.h

void R MAIN UserInit(void) **Declaration** Initializes the main function. **Explanation** 

None **Arguments** Return value None

# R\_EEL\_Initialize

**Synopsis** Initialization of EEL Header r eel function.h

r\_cg\_userdefine.h

**Declaration** uint8\_t R\_EEL\_Initialize(void)

Performs the preparation processing like initialization of RAM before starting **Explanation** 

RENESAS

EEPROM emulation.

**Arguments** None

Normal response: RET OK Return value

Abnormal termination: RET NG DEVICE

## Integrate External EEPROM IC Functionality into MCU by Using Data

Flash Memory (EEPROM Emulation Library)

R\_EEL\_ReadData

RL78/L13

SynopsisRead by EELHeaderr eel function.h

r cg userdefine.h

**Declaration** uint8\_t R\_EEL\_ReadData(uint8\_t id, uint8\_t\* pdata)

**Explanation** Reads data from data flash memory.

Arguments uint8\_t id Data ID to be read

uint8\_t\* pdata The pointer of the buffer where the read data is stored.

Return value · Normal response: RET\_OK

Abnormal termination: RET\_NG\_DEVICE

No data: RET NG NODATA

## R\_EEL\_CheckDataRange

Synopsis Valid range check of LED blinking data

Header r\_eel\_function.h

**Declaration** uint8\_t R\_EEL\_CheckDataRange(uint8\_t data)

**Explanation** Checks whether LED blinking data is in the valid range. **Arguments** uint8\_t data Object data of the check

**Return value** Within the range: RET\_OK

Outside of the range: RET\_NG\_RANGE

### R EEL CheckStatus

Synopsis EEL Function Status Check

Header r\_eel\_function.h

r cg userdefine.h

**Declaration** uint8\_t R\_EEL\_CheckStatus(eel\_request\_t\* request\_pstr )

**Explanation** Checks the execution status of EEL.

It is called immediately after performing EEL Execute.

**Arguments** eel request t\* The argument when EEL Execute is executed.

request pstr

Return value · Normal response: RET\_OK

Abnormal termination: RET\_NG\_DEVICE

No data: RET\_NG\_NODATA

### R TAU0 Channel1 Start

SynopsisEnabling TAU01Headerr\_cg\_timer.h

**Declaration** void R\_TAU0\_Channel1\_Start(void)

**Explanation** Starts the count of TAU01.

Arguments None Return value None

## Integrate External EEPROM IC Functionality into MCU by Using Data

Flash Memory (EEPROM Emulation Library)

r\_tau0\_channel1\_interrupt

RL78/L13

Synopsis TAU01 interrupt handler

**Header** r\_cg\_timer.h

r\_eel\_function.h

**Declaration** interrupt static void r tau0 channel1 interrupt(void)

**Explanation** Switches LED between ON/OFF and decrements the remaining times of LED

blinking

Target LED for blinking is switches to another LED when blinking is completed.

Arguments None Return value None

## R\_TAU0\_Channel1\_Stop

Synopsis Disabling TAU01
Header r\_cg\_timer.h

**Declaration** void R\_TAU0\_Channel1\_Stop(void)

**Explanation** Stops the count of TAU01.

Arguments None Return value None

## R\_INTC0\_Start

Synopsis Enabling INTP0
Header r\_cg\_intp.h

Declarationvoid R\_INTC0\_Start(void)ExplanationEnables INTP0 interruption.

Arguments None Return value None

## r\_intc0\_interrupt

Synopsis INTP0 interrupt handler

Header r\_cg\_intp.h

r\_cg\_timer.h

**Declaration** \_\_interrupt static void r\_intc0\_interrupt(void)

**Explanation** Starts the operation of TAU00.

Arguments None Return value None

## R\_TAU0\_Channel0\_Start

SynopsisEnabling TAU00Headerr\_cg\_timer.h

**Declaration** void R\_TAU0\_Channel0\_Start(void)

**Explanation** Starts the count of TAU00.

Arguments None Return value None

## Integrate External EEPROM IC Functionality into MCU by Using Data

Flash Memory (EEPROM Emulation Library)

## r\_tau0\_channel0\_interrupt

RL78/L13

**Synopsis** TAU00 interrupt handler

Header r cg timer.h

r eel function.h

interrupt static void r tau0 channel0 interrupt(void) **Declaration** Checks the state of SW1 and starts to blink LED. **Explanation** 

**Arguments** None None Return value

## R\_EEL\_WriteData

**Synopsis** Write by EEL Header r\_eel\_function.h

r cg userdefine.h

**Declaration** uint8 t R EEL WriteData(uint8 t id, uint8 t\* pdata)

Writes data to the data flash memory. **Explanation** 

**Arguments** uint8\_t id Data ID to be written

> uint8 t\* pdata The pointer of the buffer where the data is written.

Normal response: RET OK Return value

Abnormal termination: RET NG DEVICE

## R\_TAU0\_Channel0\_Stop

Disabling TAU00 **Synopsis** Header r cg timer.h

void R TAU0 Channel0 Stop(void) **Declaration** 

Stops the count of TAU00. **Explanation** 

**Arguments** None Return value None

## R\_INTC0\_Stop

Disabling INTP0 **Synopsis** Header r\_cg\_intp.h

void R\_INTC0\_Stop(void) **Declaration** Disables INTP0 interruption. **Explanation** 

**Arguments** None None Return value

## R LVD InterruptMode Start

**Enabling LVD interruption Synopsis** 

r\_cg\_lvd.h Header

void R LVD InterruptMode Start(void) **Declaration** 

Enables LVD interruption. **Explanation** 

**Arguments** None None Return value

# Integrate External EEPROM IC Functionality into MCU by Using Data Flash Memory (EEPROM Emulation Library)

r\_lvd\_interrupt

RL78/L13

Synopsis LVD interrupt handler

Header r\_cg\_lvd.h

r\_eel\_function.h

**Declaration** \_\_interrupt static void r\_lvd\_interrupt(void)

**Explanation** Sets the low voltage detection flag

Arguments None Return value None

FDL Init

Synopsis Initialization of FDL

Header fdl.h

**Declaration** fdl\_status\_t \_\_far FDL\_Init(const \_\_far descriptor\_t\* descriptor\_pstr)

**Explanation** Initializes FDL.

(This is a FDL library function.)

**Arguments** const far descriptor t\* It is a pointer to the descriptor table.

descriptor pstr

**Return value** · Normal termination: FDL\_OK

Initialization error: FDL\_ERR\_CONFIGURATION

FDL\_Open

Synopsis FDL set up

**Header** fdl.h

**Declaration** void far FDL Open(void)

**Explanation** Sets up FDL.

(This is a FDL library function.)

Arguments None Return value None

FDL Close

Synopsis Stop FDL Header fdl.h

**Declaration** void \_\_far FDL\_Close(void)

**Explanation** Stops FDL.

(This is a FDL library function.)

Arguments None Return value None

June. 24. 22



# Integrate External EEPROM IC Functionality into MCU by Using Data Flash Memory (EEPROM Emulation Library)

EEL\_Init

RL78/L13

Synopsis Initialization of RAM used by EEL

**Header** eel.h

**Declaration** eel\_status\_t \_\_far EEL\_Init(void)

**Explanation** Initializes RAM which is used for EEPROM emulation.

(This is an EEL library function.)

Arguments None

Return value Normal termination: EEL\_OK

Initialization error: EEL\_ERR\_CONFIGURATION

EEL\_Open

Synopsis EEL set up Header eel.h

**Declaration** void \_\_far EEL\_Open(void)

**Explanation** Changes into the state where EEPROM emulation can be performed.

(This is an EEL library function.)

Arguments None Return value None

EEL\_Close

Synopsis Stop EEL Header eel.h

**Declaration** void far EEL Close(void)

**Explanation** This function makes the EEPROM emulation unexecutable.

(This is an EEL library function.)

Arguments None Return value None

EEL\_Execute

**Synopsis** Execution of the data flash operation by each command

**Header** eel.h

**Declaration** void \_\_far EEL\_Execute(\_\_near eel\_request\_t\* request\_pstr)

**Explanation** Each type of processing for performing EEPROM emulation operations is specified

for this function as an argument in the command format, and the processing is

executed.

(This is an EEL library function.)

**Arguments** \_\_near eel\_request\_t\* It is a pointer to the request structure.

request\_pstr

Return value None



EEL\_Handler

Synopsis Controls the EEL while it is running

**Header** eel.h

**Declaration** void \_\_far EEL\_Handler(void)

**Explanation** This function continues executing the EEPROM emulation processing specified for

the EEL\_Execute function.

(This is an EEL library function.)

Arguments None Return value None

EEL\_GetSpace

Synopsis Checks free space in the EEL block

**Header** eel.h

**Declaration** eel\_status\_t \_\_far EEL\_GetSpace(\_\_near eel\_u16\* space\_pu16)

**Explanation** This obtains the free EEL block space.

(This is an EEL library function.)

**Arguments** near eel u16\* The address at which the free space information of the

space pu16 current active block is input.

**Return value** Normal termination: EEL\_OK

EEL\_Init has not been executed: EEL\_ERR\_INITIALIZATION

RENESAS

The EEL CMD STARTUP command

has not finished normally: EEL\_ERR\_ACCESS\_LOCKED A command is being executed: EEL\_ERR\_REJECTED

## 6.8 Flowcharts

## 6.8.1 Overall Flowchart

Figure 6.2 shows the overall flow of the sample program described in this application note.

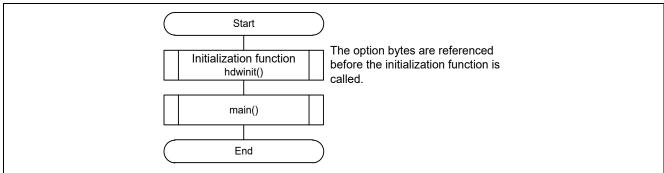


Figure 6.2 Overall Flowchart

## 6.8.2 Initialization of Peripheral Functions

Figure 6.3 shows the initialization of peripheral function.

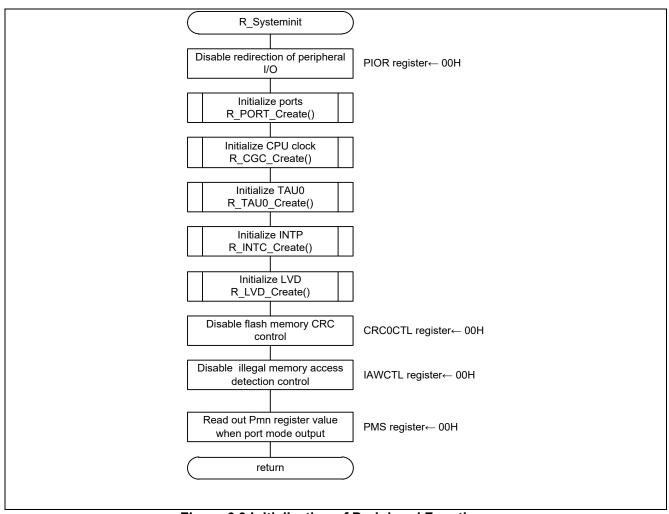


Figure 6.3 Initialization of Peripheral Functions

RENESAS

## **6.8.3** Initialization of Ports

Figure 6.4 shows the initialization of ports.

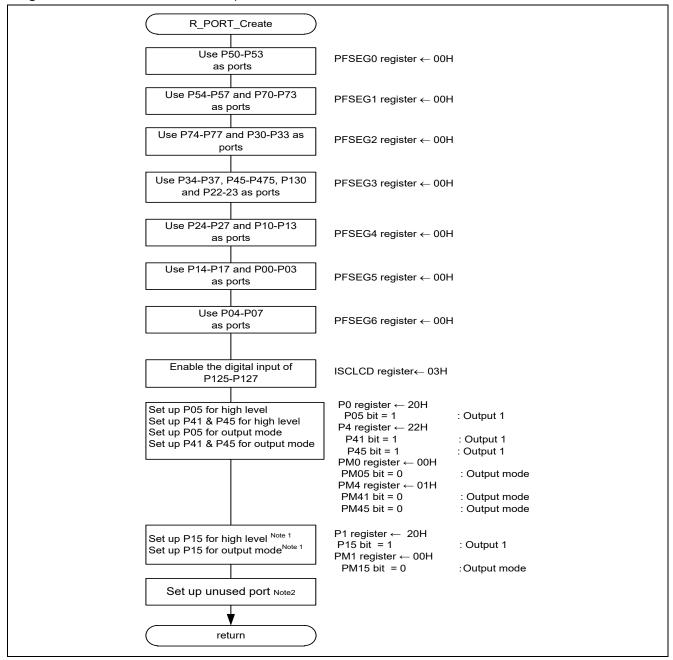


Figure 6.4 Initialization of ports

Note 1: This is a setup which makes unused LED switch off.

Note 2: Refer to "RL78/L13 User's Manual: Hardware" for the setup of the unused ports.

Caution: Provide proper treatment for unused pins so that their electrical specifications are observed.

Connect each of any unused input-only ports to VDD or Vss via a separate resistor.

## 6.8.4 Initialization of CPU Clock

Figure 6.5 shows the initialization of CPU clock.

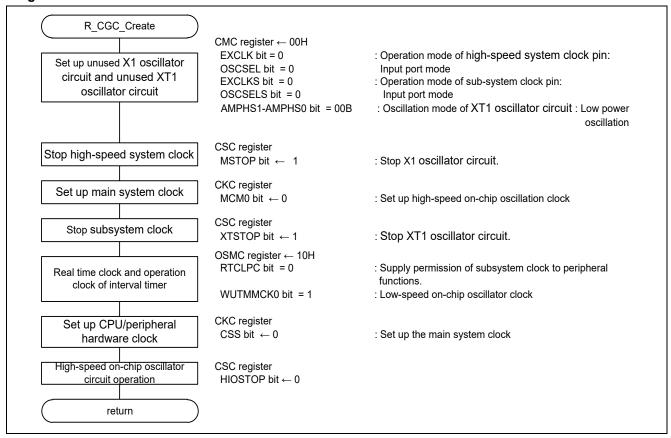


Figure 6.5 Initialization of CPU Clock

## 6.8.5 Initialization of TAU0

Figure 6.6 and Figure 6.7 show the initialization of TAU0.

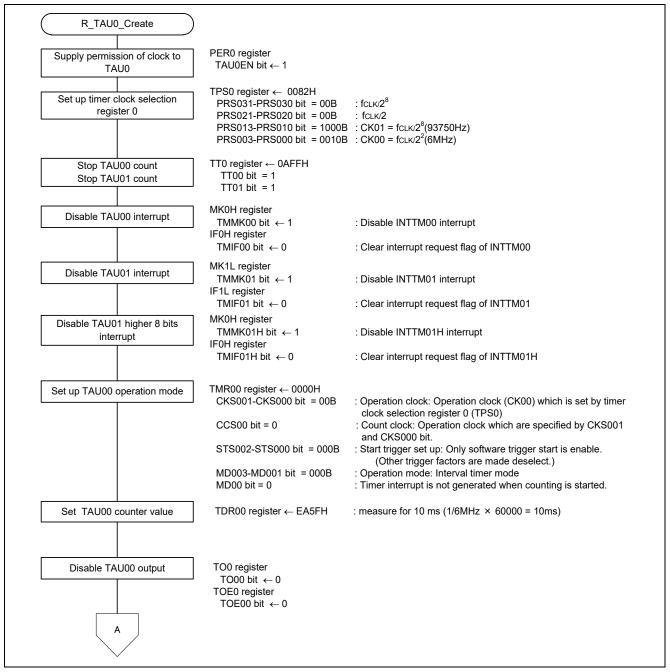


Figure 6.6 Initialization of TAU0 (1/2)

RENESAS

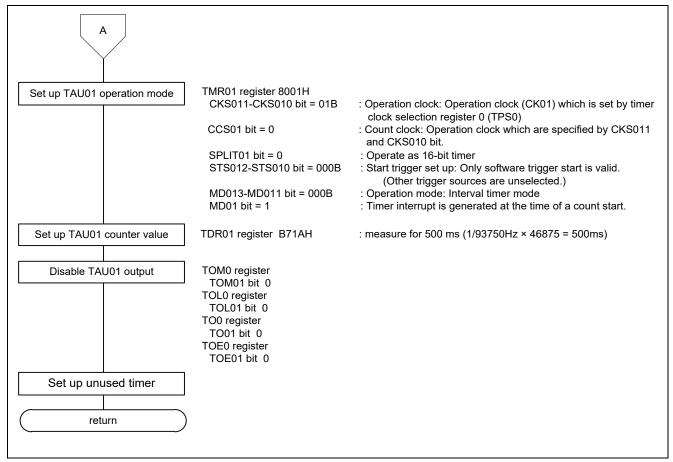


Figure 6.7 Initialization of TAU0 (2/2)

## 6.8.6 Initialization of INTP

Figure 6.8 shows the initialization of INTP.

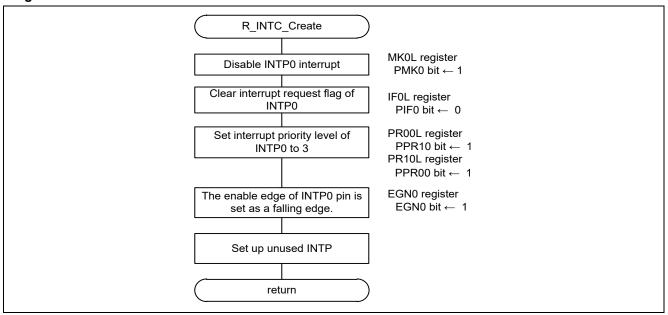


Figure 6.8 Initialization of INTP

## 6.8.7 Initialization of LVD

Figure 6.9 shows the initialization of LVD.

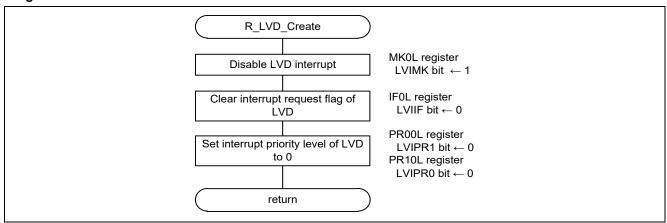


Figure 6.9 Initialization of LVD

## 6.8.8 Main Processing

Figure 6.10 and Figure 6.11 show the main processing.

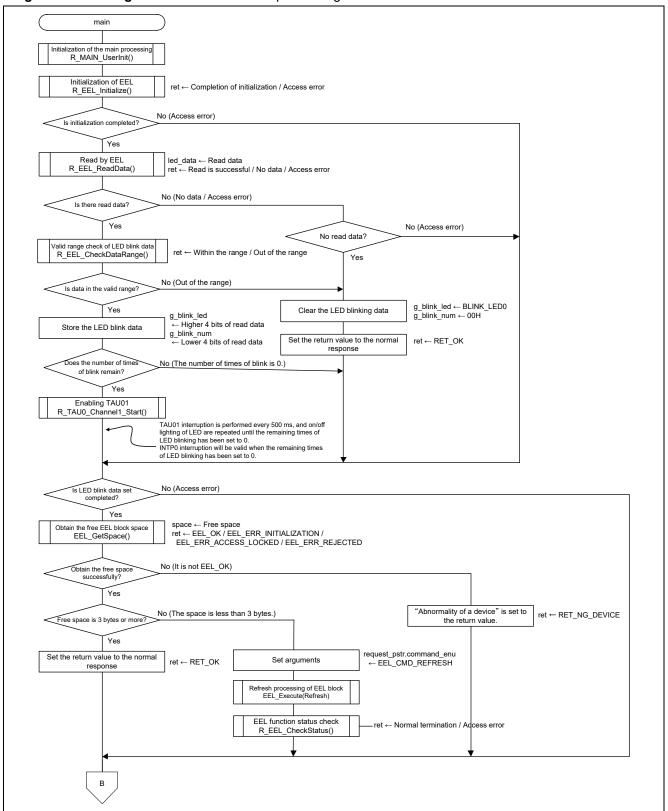


Figure 6.10 Main Processing (1/2)

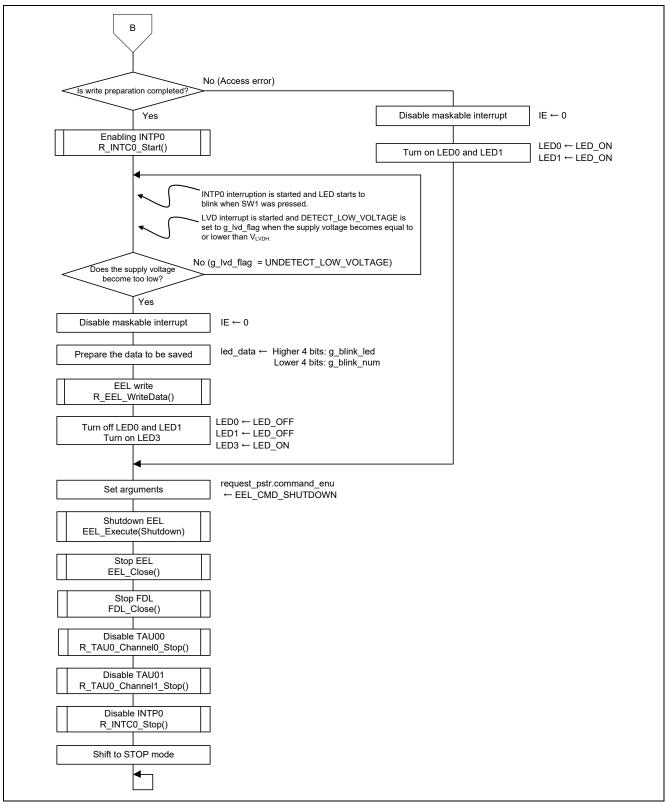


Figure 6.11 Main Processing (2/2)

#### 6.8.9 Initialization of the Main Processing

Figure 6.12 shows the initialization of the main processing.

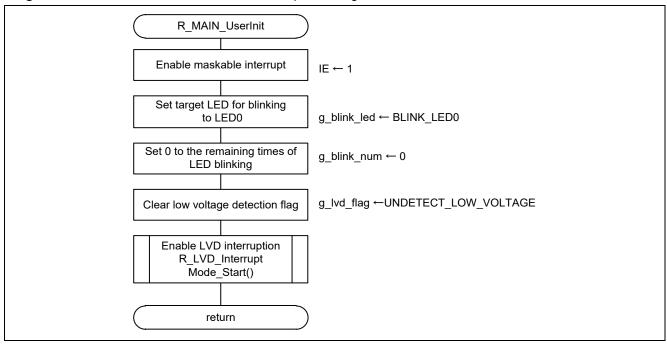


Figure 6.12 Initialization of the Main Processing

#### **Initialization of EEL** 6.8.10

Figure 6.13 shows the initialization of EEL.

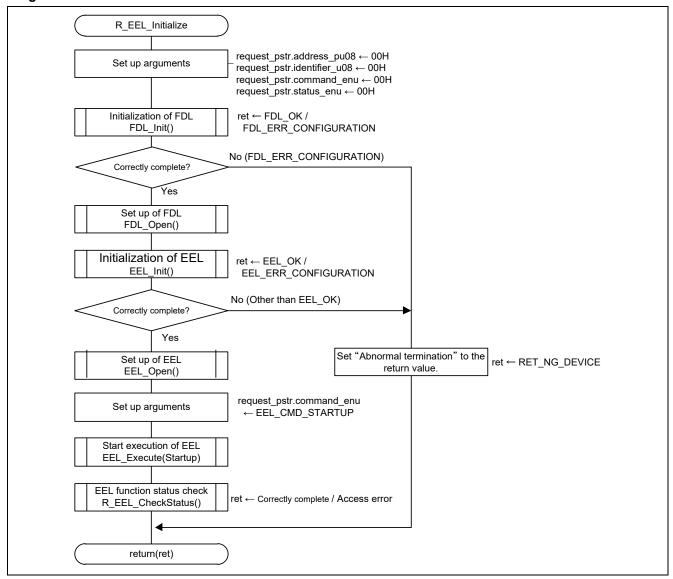


Figure 6.13 Initialization of EEL

## 6.8.11 Read Processing by EEL

Figure 6.14 shows how to read data by EEL.

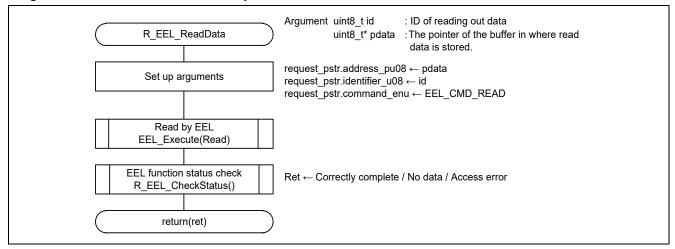


Figure 6.14 Read by EEL

## 6.8.12 Valid Range Check of LED blinking Data

Figure 6.15 shows the valid range check of LED blinking data.

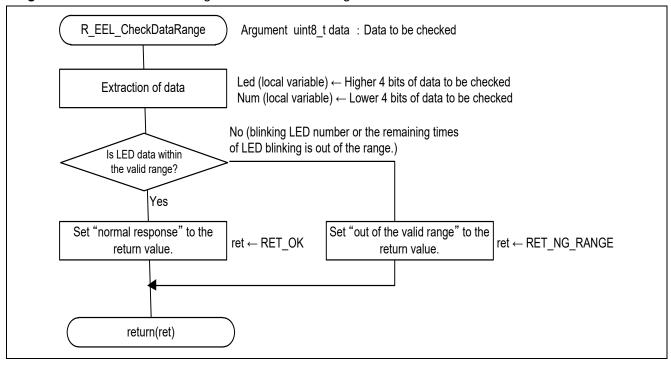


Figure 6.15 Valid Range Check of LED Blinking Data

RENESAS

#### 6.8.13 **EEL Function Status Check**

Figure 6.16 shows the EEL function status check.

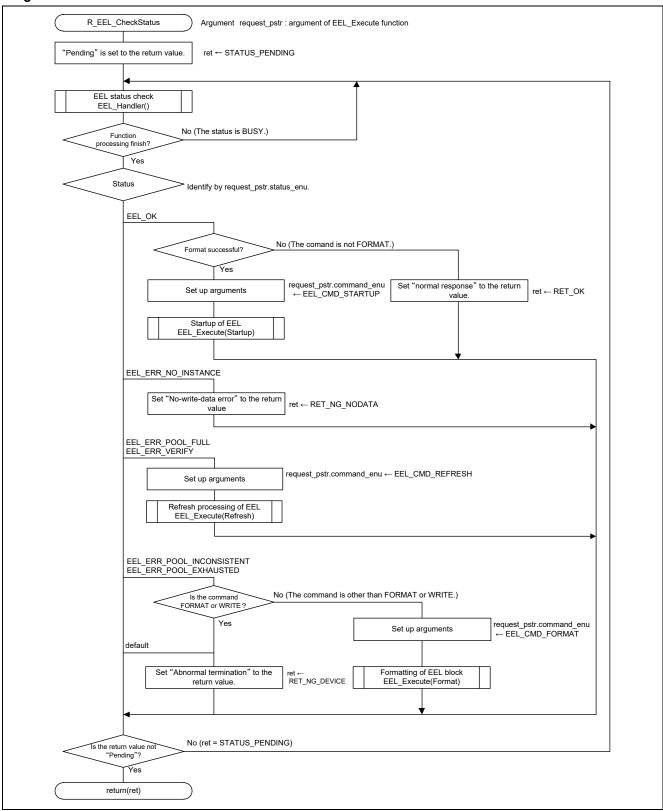


Figure 6.16 EEL Function Status Check

## 6.8.14 Enabling TAU01

Figure 6.17 shows how to enable TAU01.

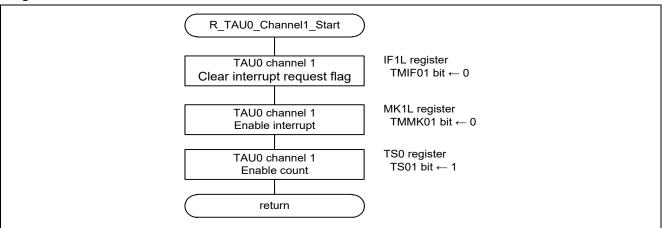


Figure 6.17 Enabling TAU01

#### 6.8.15 **TAU01 Interrupt Handler**

Figure 6.18 shows the flowchart of the TAU01 interrupt handler.

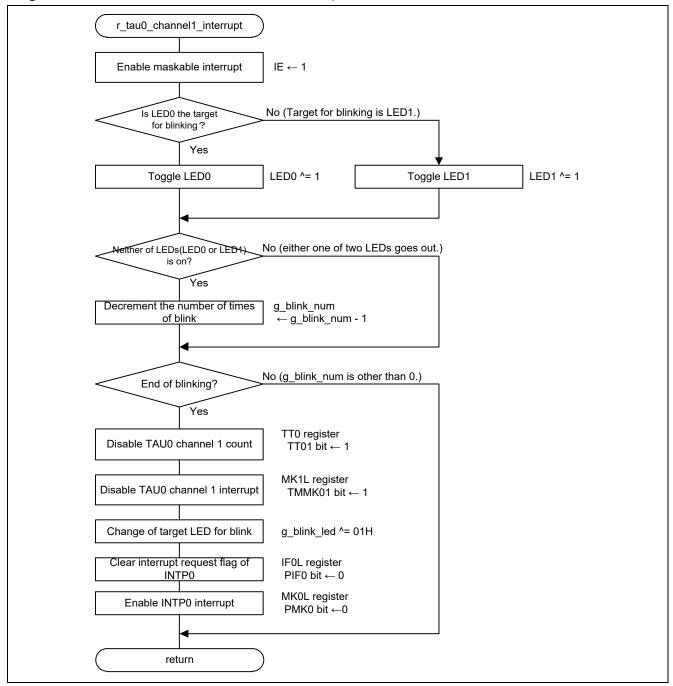


Figure 6.18 TAU01 Interrupt Handler

#### 6.8.16 **Disabling TAU01**

Figure 6.19 shows how to disable TAU01.

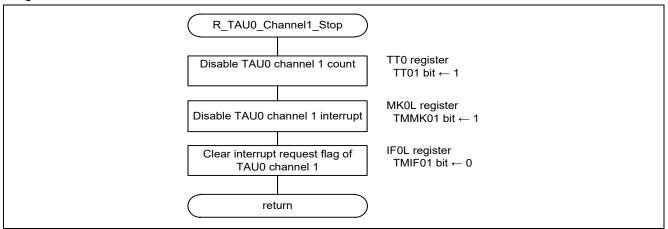


Figure 6.19 Disabling TAU01

#### 6.8.17 **Enabling INTP0**

Figure 6.20 shows how to enable INTP0.

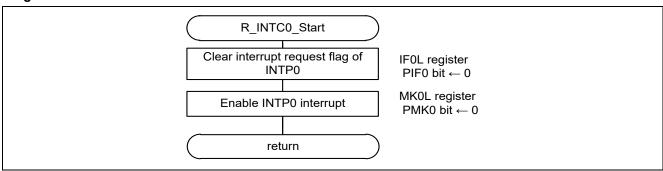


Figure 6.20 Enabling INTP0

R01AN6457EJ0100 Rev.1.00 June. 24. 22

#### **INTP0** Interrupt Handler 6.8.18

Figure 6.21 shows the flowchart of the INTP0 interrupt handler.

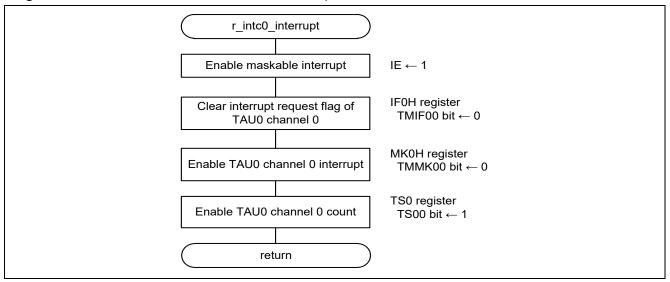


Figure 6.21 INTP0 Interrupt Handler

#### 6.8.19 **Enabling TAU00**

Figure 6.22 shows how to enable TAU00.

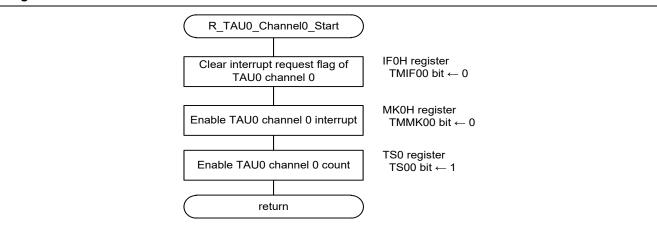


Figure 6.22 Enabling TAU00

RENESAS

June. 24. 22

#### **TAU00** interrupt handler 6.8.20

Figure 6.23 shows the flowchart of the TAU00 interrupt handler.

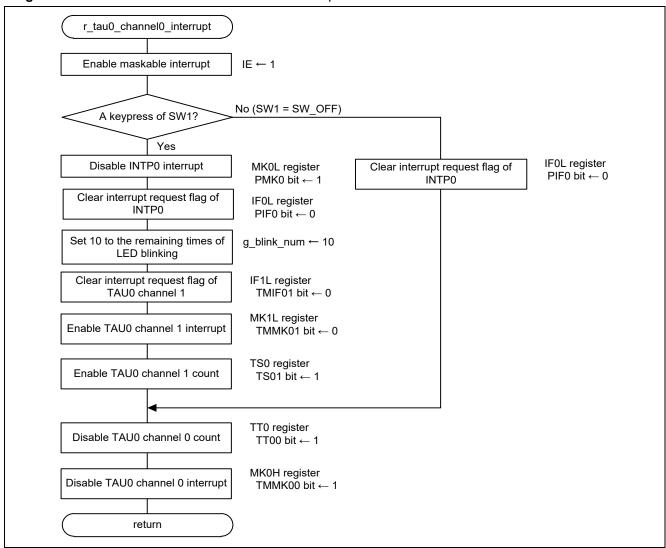


Figure 6.23 TAU00 interrupt handler

#### 6.8.21 Write by EEL

Figure 6.24 shows how to write data by EEL.

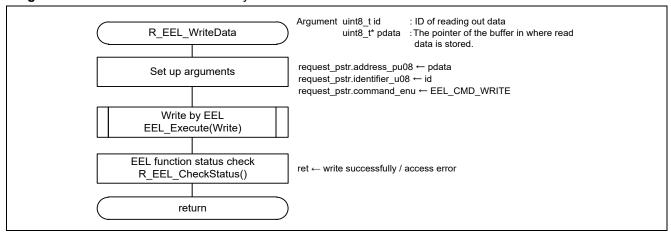


Figure 6.24 Write by EEL

#### 6.8.22 **Disabling TAU00**

Figure 6.25 shows how to disable TAU00.

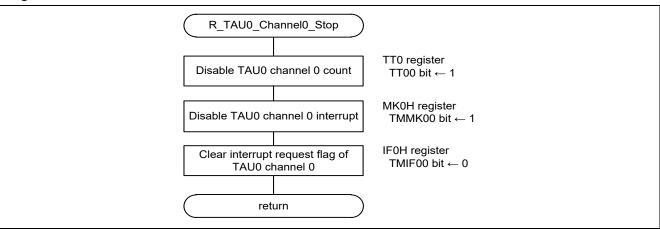


Figure 6.25 Disabling TAU00

#### 6.8.23 **Disabling INTP0**

Figure 6.26 shows how to disable INTP0.

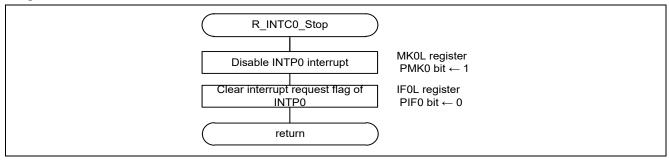
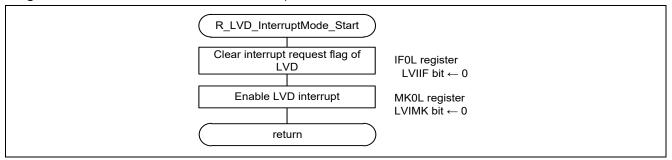


Figure 6.26 Disabling INTP0

RENESAS June. 24. 22

#### 6.8.24 **Enabling LVD Interrupt**

Figure 6.27 shows how to enable LVD interrupt.



**Figure 6.27 Enabling LVD Interrupt** 

#### 6.8.25 LVD interrupt handler

Figure 6.28 shows the flowchart of the LVD interrupt handler.

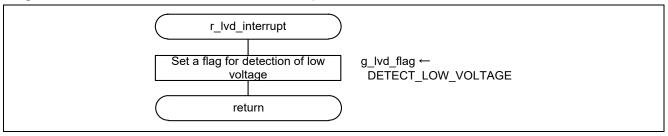


Figure 6.28 LVD interrupt handler

RENESAS June. 24. 22

## 6.9 How to Import EEL into the Software Project

How to import EEL files used by this application into the software project is indicated below.

## 6.9.1 CS+ Version

- (1) The following files are copied to the root directory of a project.
  - · fdl.h
  - · fdl types.h
  - · fdl.lib
  - · eel.h
  - · eel types.h
  - eel.lib
- (2) Right-clicks "File" at the project tree of CS+ and select the file copied according to the extension (.h, .lib, dr) by clicking "Add" and "Add an existing file".

### Caution

Please do not import the file in the directory smprl78 included in EEL. Be sure to use the file included in the sample code. (e.g. eel\_descriptor.c)

When the file has been overwritten, correct according to "0 EEL Initial Values to be Set by User".

## 6.9.2 e2studio Version

- (1) The following files are copied to src directory.
  - fdl.h
  - · fdl\_types.h
  - fdl.lib
  - · eel.h
  - · eel types.h
  - · eel.lib
- (2) Select "Update" by right-click project name at project explorer of e2studio.

### Caution

Please do not import the file in the directory smp included in FDL/EEL. Be sure to use the file included in the sample code. (e.g. eel\_descriptor.c)

When the file has been overwritten, correct according to "0 EEL Initial Values to be Set by User".

## 6.9.3 IAR Version

- (1) Copy the installed EEL folder to the root directory of the project.
- (2) Select "C/C++ Compiler" > "Preprocessor" from the IAR Project Options.
- (3) Specify the folders copied to the root directory up to subfolders in the "Additional include directories" field.

(Example. \$PROJ\_DIR\$\EEL\IAR\_210\EEL\Ib) (Example. \$PROJ\_DIR\$\EEL\IAR\_210\FDL\Ib)

(4) "https://github.com/IARSystems/ewrl78-linker-config-flashlibs"

Download the linker script for IAR from the GitHub page above.

- (5) Copy the following folder in the download to the user function folder.
  - · trio InkR5F100xE.icf
  - · common.icf
  - · self\_ram.icf



# RL78/L13 Integrate External EEPROM IC Functionality into MCU by Using Data Flash Memory (EEPROM Emulation Library)

(6) Rename the copied "trio InkR5F100xE.icf" to "trio IvkR5F10WMG.icf" and modify the code as follows

```
define symbol _FLASH_END = 0x1FFFF;
define symbol _RAM_START = 0xFDF00;
```

(7) Modify the copied "common.icf" as follows

```
define region OCD_ROM_RAM_AREA = msm:[from(_FRASH_END & 0x1FE00) size 0x200
```

- (8) From IAR Project Options, check "Linker" -> "Config" -> "Override Default".
- (9) Specify the modified "trio\_lvkR5F10WMG.icf".
- (10) In the "Configuration file symbol definitions," enter the corresponding EEL and FDL symbols from the "RAM reservation symbols" table at the bottom of the GitHub page.

```
(Example. __RESRVE_T02_EEL=1)
(Example. RESRVE T02 FDL=1)
```

(11) Add FDL and EEL libraries to "Linker" -> "Library" -> "Additional Libraries" from the IAR Project Options.

```
(Example. $PROJ_DIR$\EEL\IAR_210\EEL\Iib\eel.a) (Example. $PROJ_DIR$\EEL\IAR_210\FDL\Iib\fdl.a)
```

Note: Directories included in FDL/EEL must be modified according to "2.3EEL Initial Values to be Set by User".

R01AN6457EJ0100 Rev.1.00 June. 24. 22

#### 6.10 **Modification of the Sample Code**

When re-execute code generation, correction of files and projects may be needed as follows.

Target IDE: CS+ version, e2studio version

File name: r\_cg\_main.c

Fix location: R\_MAIN\_UserInit();.

Delete R\_MAIN\_Userinit(); above the Start user code. generated in the main function.

```
void main(void)
□{
     R_MAIN_UserInit();

/* Start user code. Do not edit comment generated here */
 void main(void)
₽{
      /* Start user code. Do not edit comment generated here */
```

R01AN6457EJ0100 Rev.1.00 June. 24. 22



# RL78/L13 Integrate External EEPROM IC Functionality into MCU by Using Data Flash Memory (EEPROM Emulation Library)

<del>7</del>:

## 7. Sample Code

The sample code is available on the Renesas Electronics Website.

## 8. Documents for Reference

RL78/L13 User's Manual: Hardware RL78 Family User's Manual: Software

(The latest versions of the documents are available on the Renesas Electronics Website.)

Technical Updates/Technical Brochures

(The latest versions of the documents are available on the Renesas Electronics Website.)

All trademarks and registered trademarks are the property of their respective owners.



## **Revision History**

## Description

Rev.	Date	Page	Summary
1.00	June. 24. 22	-	First edition issued

# General Precautions in the Handling of Microprocessing Unit and Microcontroller Unit Products

The following usage notes are applicable to all Microprocessing unit and Microcontroller unit products from Renesas. For detailed usage notes on the products covered by this document, refer to the relevant sections of the document as well as any technical updates that have been issued for the products.

1. Precaution against Electrostatic Discharge (ESD)

A strong electrical field, when exposed to a CMOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop the generation of static electricity as much as possible, and quickly dissipate it when it occurs. Environmental control must be adequate. When it is dry, a humidifier should be used. This is recommended to avoid using insulators that can easily build up static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work benches and floors must be grounded. The operator must also be grounded using a wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions must be taken for printed circuit boards with mounted semiconductor devices.

2. Processing at power-on

The state of the product is undefined at the time when power is supplied. The states of internal circuits in the LSI are indeterminate and the states of register settings and pins are undefined at the time when power is supplied. In a finished product where the reset signal is applied to the external reset pin, the states of pins are not guaranteed from the time when power is supplied until the reset process is completed. In a similar way, the states of pins in a product that is reset by an on-chip power-on reset function are not guaranteed from the time when power is supplied until the power reaches the level at which resetting is specified.

- 3. Input of signal during power-off state
  - Do not input signals or an I/O pull-up power supply while the device is powered off. The current injection that results from input of such a signal or I/O pull-up power supply may cause malfunction and the abnormal current that passes in the device at this time may cause degradation of internal elements. Follow the guideline for input signal during power-off state as described in your product documentation.
- 4. Handling of unused pins

Handle unused pins in accordance with the directions given under handling of unused pins in the manual. The input pins of CMOS products are generally in the high-impedance state. In operation with an unused pin in the open-circuit state, extra electromagnetic noise is induced in the vicinity of the LSI, an associated shoot-through current flows internally, and malfunctions occur due to the false recognition of the pin state as an input signal become possible.

5. Clock signals

After applying a reset, only release the reset line after the operating clock signal becomes stable. When switching the clock signal during program execution, wait until the target clock signal is stabilized. When the clock signal is generated with an external resonator or from an external oscillator during a reset, ensure that the reset line is only released after full stabilization of the clock signal. Additionally, when switching to a clock signal produced with an external resonator or by an external oscillator while program execution is in progress, wait until the target clock signal is stable.

- 6. Voltage application waveform at input pin
  - Waveform distortion due to input noise or a reflected wave may cause malfunction. If the input of the CMOS device stays in the area between  $V_{IL}$  (Max.) and  $V_{IH}$  (Min.) due to noise, for example, the device may malfunction. Take care to prevent chattering noise from entering the device when the input level is fixed, and also in the transition period when the input level passes through the area between  $V_{IL}$  (Max.) and  $V_{IH}$  (Min.).
- 7. Prohibition of access to reserved addresses
  - Access to reserved addresses is prohibited. The reserved addresses are provided for possible future expansion of functions. Do not access these addresses as the correct operation of the LSI is not guaranteed.
- 8. Differences between products
  - Before changing from one product to another, for example to a product with a different part number, confirm that the change will not lead to problems. The characteristics of a microprocessing unit or microcontroller unit products in the same group but having a different part number might differ in terms of internal memory capacity, layout pattern, and other factors, which can affect the ranges of electrical characteristics, such as characteristic values, operating margins, immunity to noise, and amount of radiated noise. When changing to a product with a different part number, implement a system-evaluation test for the given product.

## **Notice**

- 1. Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation or any other use of the circuits, software, and information in the design of your product or system. Renesas Electronics disclaims any and all liability for any losses and damages incurred by you or third parties arising from the use of these circuits, software, or information.
- 2. Renesas Electronics hereby expressly disclaims any warranties against and liability for infringement or any other claims involving patents, copyrights, or other intellectual property rights of third parties, by or arising from the use of Renesas Electronics products or technical information described in this document, including but not limited to, the product data, drawings, charts, programs, algorithms, and application examples.
- 3. No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights of Renesas Electronics or others
- 4. You shall be responsible for determining what licenses are required from any third parties, and obtaining such licenses for the lawful import, export, manufacture, sales, utilization, distribution or other disposal of any products incorporating Renesas Electronics products, if required.
- 5. You shall not alter, modify, copy, or reverse engineer any Renesas Electronics product, whether in whole or in part. Renesas Electronics disclaims any and all liability for any losses or damages incurred by you or third parties arising from such alteration, modification, copying or reverse engineering.
- 6. Renesas Electronics products are classified according to the following two quality grades: "Standard" and "High Quality". The intended applications for each Renesas Electronics product depends on the product's quality grade, as indicated below.
  - "Standard": Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools; personal electronic equipment; industrial robots; etc.
  - "High Quality": Transportation equipment (automobiles, trains, ships, etc.); traffic control (traffic lights); large-scale communication equipment; key financial terminal systems; safety control equipment; etc.

Unless expressly designated as a high reliability product or a product for harsh environments in a Renesas Electronics data sheet or other Renesas Electronics document, Renesas Electronics products are not intended or authorized for use in products or systems that may pose a direct threat to human life or bodily injury (artificial life support devices or systems; surgical implantations; etc.), or may cause serious property damage (space system; undersea repeaters; nuclear power control systems; aircraft control systems; key plant systems; military equipment; etc.). Renesas Electronics disclaims any and all liability for any damages or losses incurred by you or any third parties arising from the use of any Renesas Electronics product that is inconsistent with any Renesas Electronics data sheet, user's manual or other Renesas Electronics document.

- 7. No semiconductor product is absolutely secure. Notwithstanding any security measures or features that may be implemented in Renesas Electronics hardware or software products, Renesas Electronics shall have absolutely no liability arising out of any vulnerability or security breach, including but not limited to any unauthorized access to or use of a Renesas Electronics product or a system that uses a Renesas Electronics product. RENESAS ELECTRONICS DOES NOT WARRANT OR GUARANTEE THAT RENESAS ELECTRONICS PRODUCTS, OR ANY SYSTEMS CREATED USING RENESAS ELECTRONICS PRODUCTS WILL BE INVULNERABLE OR FREE FROM CORRUPTION, ATTACK, VIRUSES, INTERFERENCE, HACKING, DATA LOSS OR THEFT, OR OTHER SECURITY INTRUSION ("Vulnerability Issues"). RENESAS ELECTRONICS DISCLAIMS ANY AND ALL RESPONSIBILITY OR LIABILITY ARISING FROM OR RELATED TO ANY VULNERABILITY ISSUES. FURTHERMORE, TO THE EXTENT PERMITTED BY APPLICABLE LAW, RENESAS ELECTRONICS DISCLAIMS ANY AND ALL WARRANTIES, EXPRESS OR IMPLIED, WITH RESPECT TO THIS DOCUMENT AND ANY RELATED OR ACCOMPANYING SOFTWARE OR HARDWARE, INCLUDING BUT NOT LIMITED TO THE IMPLIED WARRANTIES OF MERCHANTABILITY, OR FITNESS FOR A PARTICULAR PURPOSE.
- 8. When using Renesas Electronics products, refer to the latest product information (data sheets, user's manuals, application notes, "General Notes for Handling and Using Semiconductor Devices" in the reliability handbook, etc.), and ensure that usage conditions are within the ranges specified by Renesas Electronics with respect to maximum ratings, operating power supply voltage range, heat dissipation characteristics, installation, etc. Renesas Electronics disclaims any and all liability for any malfunctions, failure or accident arising out of the use of Renesas Electronics products outside of such specified ranges.
- 9. Although Renesas Electronics endeavors to improve the quality and reliability of Renesas Electronics products, semiconductor products have specific characteristics, such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Unless designated as a high reliability product or a product for harsh environments in a Renesas Electronics data sheet or other Renesas Electronics document, Renesas Electronics products are not subject to radiation resistance design. You are responsible for implementing safety measures to guard against the possibility of bodily injury, injury or damage caused by fire, and/or danger to the public in the event of a failure or malfunction of Renesas Electronics products, such as safety design for hardware and software, including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult and impractical, you are responsible for evaluating the safety of the final products or systems manufactured by you.
- 10. Please contact a Renesas Electronics sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. You are responsible for carefully and sufficiently investigating applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive, and using Renesas Electronics products in compliance with all these applicable laws and regulations. Renesas Electronics disclaims any and all liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations.
- 11. Renesas Electronics products and technologies shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations. You shall comply with any applicable export control laws and regulations promulgated and administered by the governments of any countries asserting jurisdiction over the parties or transactions.
- 12. It is the responsibility of the buyer or distributor of Renesas Electronics products, or any other party who distributes, disposes of, or otherwise sells or transfers the product to a third party, to notify such third party in advance of the contents and conditions set forth in this document.
- 13. This document shall not be reprinted, reproduced or duplicated in any form, in whole or in part, without prior written consent of Renesas Electronics.
- 14. Please contact a Renesas Electronics sales office if you have any questions regarding the information contained in this document or Renesas Electronics products.
- (Note1) "Renesas Electronics" as used in this document means Renesas Electronics Corporation and also includes its directly or indirectly controlled subsidiaries.
- (Note2) "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics.

(Rev.5.0-1 October 2020)

## **Corporate Headquarters**

TOYOSU FORESIA, 3-2-24 Toyosu, Koto-ku, Tokyo 135-0061, Japan www.renesas.com

## **Trademarks**

Renesas and the Renesas logo are trademarks of Renesas Electronics Corporation. All trademarks and registered trademarks are the property of their respective owners.

### Contact information

For further information on a product, technology, the most up-to-date version of a document, or your nearest sales office, please visit: www.renesas.com/contact/.

